

# Infineon<sup>®</sup> Basic LED Driver

# TLD1125EL

1 Channel High Side Current Source

## Data Sheet

Rev. 1.0, 2013-08-08

# Automotive



1	Overview	3
2	Block Diagram	5
<b>3</b> 3.1 3.2	Pin Configuration         Pin Assignment         Pin Definitions and Functions	6
<b>4</b> 4.1 4.2 4.3	General Product Characteristics         Absolute Maximum Ratings         Functional Range         Thermal Resistance	8 9
<b>5</b> 5.1 5.2 5.3 5.3.1 5.3.2	EN Pin EN Function Internal Supply Pin EN Unused EN - Pull Up to VS EN - Direct Connection to VS	10 11 12 12
<b>6</b> 6.1 6.2 6.3	PWMI Pin         PWM Dimming         Internal PWM Unit         Electrical Characteristics Internal Supply / EN / PWMI Pin	13 14
<b>7</b> 7.1 7.2	IN_SET Pin Output Current Adjustment via RSET Smart Input Pin	18
<b>8</b> 8.1 8.2 8.3	ST Pin Diagnosis Selector Diagnosis Output Disable Input	21 21
9	D Pin	23
<b>10</b> 10.1 10.2 10.3	Load Diagnosis         Open Load         Short Circuit to GND detection         Electrical Characteristics IN_SET Pin and Load Diagnosis	24 26
<b>11</b> 11.1 11.1.1 11.1.2 11.2	Power Stage         Protection         Over Load Behavior         Reverse Battery Protection         Electrical Characteristics Power Stage	30 30 30
<b>12</b> 12.1	Application Information           Further Application Information	
13	Package Outlines	34
14	Revision History	35



## 1 Channel High Side Current Source Basic LED Driver

## TLD1125EL



## 1 Overview

#### Features

- 1 Channel device with integrated output stage (current source), optimized to drive LEDs
- Output current up to 360mA
- Low current consumption in sleep mode
- PWM-operation supported via VS- and EN-pin
- Integrated PWM dimming engine to provide two LED brightness levels without external logic (e.g. µC)
- Output current adjustable via external low power resistor and possibility to connect PTC resistor for LED protection during over temperature conditions
- Reverse polarity protection
- Overload protection
- Undervoltage detection
- Open load and short circuit to GND diagnosis
- Wide temperature range: -40 °C < T<sub>i</sub> < 150 °C</li>
- PG-SSOP14 package with exposed heatslug
- Green Product (RoHS compliant)
- AEC Qualified

#### Description

The Basic LED Driver TLD1125EL is a one channel high side driver IC with integrated output stage. It is designed to control LEDs with a current up to 360 mA. In typical automotive applications the device is capable to drive i.e. 3 red LEDs with a current up to 180 mA, which is limited by thermal cooling aspects. The output current is controlled practically independent of load and supply voltage changes.

#### Table 1Product Summary

Operating voltage	V <sub>S(nom)</sub>	5.5 V 40 V
Maximum voltage	$V_{ m S(max)}$ $V_{ m OUT(max)}$	40 V
Nominal output (load) current		180 mA when using a supply voltage range of 8V - 18V (e.g. Automotive car battery). Currents up to $I_{\text{OUT}(\text{max})}$ possible in applications with low thermal resistance $R_{\text{thJA}}$
Maximum output (load) current	I <sub>OUT(max)</sub>	360 mA; depending on thermal resistance $R_{\rm thJA}$

Туре	Package	Marking		
TLD1125EL	PG-SSOP14	TLD1125EL		



PG-SSOP14



#### Overview

#### Table 1 Product Summary

Output current accuracy at $R_{\text{SET}}$ = 12 k $\Omega$	k <sub>LT</sub>	$2250\pm7\%$
Current consumption in sleep mode	$I_{\rm S(sleep,typ)}$	0.1 μΑ

#### **Protective functions**

- ESD protection
- Under voltage lock out
- Over Load protection
- Over Temperature protection
- Reverse Polarity protection

#### **Diagnostic functions**

- OL detection
- SC to Vs (indicated by OL diagnosis)
- SC to GND detection

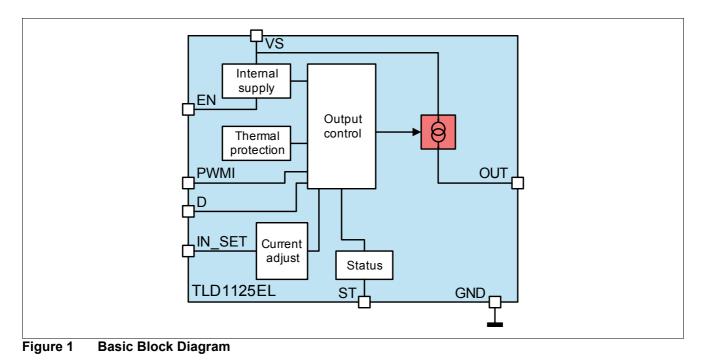
#### Applications

Designed for exterior LED lighting applications such as tail/brake light, turn indicator, position light, side marker,... The device is also well suited for interior LED lighting applications such as ambient lighting, interior illumination and dash board lighting.



**Block Diagram** 

## 2 Block Diagram





**Pin Configuration** 

## 3 Pin Configuration

## 3.1 Pin Assignment

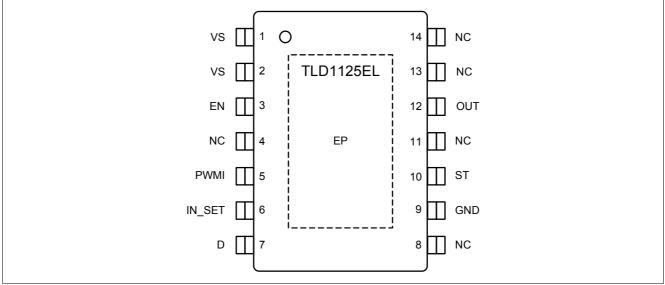


Figure 2 Pin Configuration



#### **Pin Configuration**

## 3.2 Pin Definitions and Functions

Pin	Symbol	Input/ Output	Function
1, 2	VS	-	Supply Voltage; battery supply, connect a decoupling capacitor (100 nF - 1 $\mu$ F) to GND
3	EN	I	Enable pin
4	NC	-	Pin not connected
5	PWMI	I/O	PWM Input
6	IN_SET	I/O	Input / SET pin; Connect a low power resistor to adjust the output current
7	D	I/O	Delay for open load detection
8	NC	-	Pin not connected
9	GND	-	<sup>1)</sup> Ground
10	ST	I/O	Status pin
11	NC	-	Pin not connected
12	OUT	0	Output
13	NC	-	Pin not connected
14	NC	-	Pin not connected
Exposed Pad	GND	-	<sup>1)</sup> Exposed Pad; connect to GND in application

1) Connect all GND-pins together.



## 4 General Product Characteristics

## 4.1 Absolute Maximum Ratings

#### Absolute Maximum Ratings <sup>1)</sup>

 $T_{\rm j}$  = -40 °C to +150 °C; all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol	Limit	t Values	Unit	Conditions
			Min.	Max.		
Voltage	S		<u>.</u>			+
4.1.1	Supply voltage	Vs	-16	40	V	-
4.1.2	Input voltage EN	V <sub>EN</sub>	-16	40	V	-
4.1.3	Input voltage EN related to $V_{\rm S}$	$V_{\rm EN(VS)}$	V <sub>S</sub> - 40	V <sub>S</sub> + 16	V	-
4.1.4	Input voltage EN related to $V_{\rm OUT}$ $V_{\rm EN}$ - $V_{\rm OUT}$	V <sub>EN</sub> - V <sub>OUT</sub>	-16	40	V	-
4.1.5	Output voltage	V <sub>OUT</sub>	-1	40	V	-
4.1.6	Power stage voltage $V_{PS} = V_S - V_{OUT}$	V <sub>PS</sub>	-16	40	V	-
4.1.7	Input voltage PWMI	$V_{PWMI}$	-0.3	6	V	-
4.1.8	IN_SET voltage	$V_{IN\_SET}$	-0.3	6	V	-
4.1.9	D voltage	V <sub>D</sub>	-0.3	6	V	-
4.1.10	Status voltage	V <sub>ST</sub>	-0.3	6	V	-
Current	S				-	
4.1.11	IN_SET current	I <sub>IN_SET</sub>	-	2 8	mA	– Diagnosis output
4.1.12	D current	ID	-0.5	0.5	mA	-
4.1.13	Output current	I <sub>OUT</sub>	-	390	mA	-
Temper	atures		- U-			
4.1.14	Junction temperature	$T_{\rm i}$	-40	150	°C	-
4.1.15	Storage temperature	T <sub>stg</sub>	-55	150	°C	-
ESD Su	sceptibility					
4.1.16	ESD resistivity to GND	V <sub>ESD</sub>	-2	2	kV	Human Body Model (100 pF via $1.5 \text{ k}\Omega)^{2)}$
4.1.17	ESD resistivity all pins to GND	$V_{ESD}$	-500	500	V	CDM <sup>3)</sup>
4.1.18	ESD resistivity corner pins to GND	V <sub>ESD</sub>	-750	750	V	CDM <sup>3)</sup>

1) Not subject to production test, specified by design

2) ESD susceptibility, Human Body Model "HBM" according to ANSI/ESDA/JEDEC JS-001-2011

3) ESD susceptibility, Charged Device Model "CDM" according to JESD22-C101E

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.



#### **General Product Characteristics**

## 4.2 Functional Range

Pos.	Parameter	Symbol	Limit Values		Unit	Conditions	
			Min.	Max.			
4.2.19	Supply voltage range for normal operation	$V_{\mathrm{S(nom)}}$	5.5	40	V	-	
4.2.20	Power on reset threshold	V <sub>S(POR)</sub>	-	5	V	$V_{\rm EN} = V_{\rm S}$ $R_{\rm SET} = 12 \text{ k}\Omega$ $I_{\rm OUT} = 80\% I_{\rm OUT(nom)}$ $V_{\rm OUT} = 2.5 \text{ V}$	
4.2.21	Junction temperature	T <sub>i</sub>	-40	150	°C	-	

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

#### 4.3 Thermal Resistance

Pos.	Parameter	Symbol		_imit Val	ues	Unit	Conditions
			Min.	Тур.	Max.		
4.3.1	Junction to Case	R <sub>thJC</sub>	-	8	10	K/W	1) 2)
4.3.2	Junction to Ambient 1s0p board	R <sub>thJA1</sub>				K/W	1) 3)
			-	61	-		T <sub>a</sub> = 85 °C
			-	56	-		T <sub>a</sub> = 85 °C T <sub>a</sub> = 135 °C
4.3.3	Junction to Ambient 2s2p board	R <sub>thJA2</sub>				K/W	1) 4)
			_	45	-		T <sub>a</sub> = 85 °C
			-	43	-		$T_{a} = 135 ^{\circ}\text{C}$

1) Not subject to production test, specified by design. Based on simulation results.

2) Specified  $R_{\text{thJC}}$  value is simulated at natural convection on a cold plate setup (all pins and the exposed Pad are fixed to ambient temperature).  $T_{a} = 85^{\circ}$ C, Total power dissipation 1.5 W.

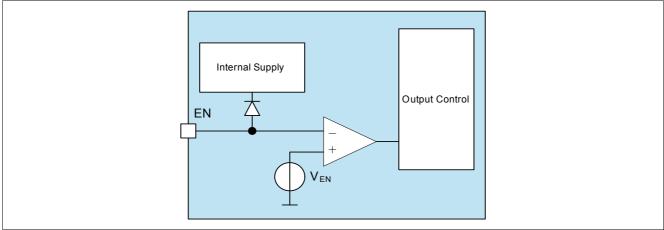
- 3) The  $R_{\text{thJA}}$  values are according to Jedec JESD51-3 at natural convection on 1s0p FR4 board. The product (chip + package) was simulated on a 76.2 x 114.3 x 1.5 mm<sup>3</sup> board with 70µm Cu, 300 mm<sup>2</sup> cooling area. Total power dissipation 1.5 W distributed statically and homogenously over power stage.
- 4) The R<sub>thJA</sub> values are according to Jedec JESD51-5,-7 at natural convection on 2s2p FR4 board. The product (chip + package) was simulated on a 76.2 x 114.3 x 1.5 mm<sup>3</sup> board with 2 inner copper layers (outside 2 x 70 μm Cu, inner 2 x 35μm Cu). Where applicable, a thermal via array under the exposed pad contacted the first inner copper layer. Total power dissipation 1.5 W distributed statically and homogenously over power stage.



**EN** Pin

## 5 EN Pin

The EN pin is a dual function pin:

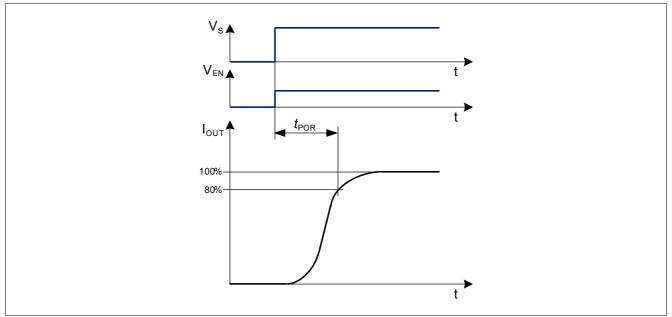


#### Figure 3 Block Diagram EN pin

Note: The current consumption at the EN-pin  $I_{EN}$  needs to be added to the total device current consumption. The total current consumption is the sum of the currents at the VS-pin  $I_{S}$  and the EN-pin  $I_{EN}$ .

## 5.1 EN Function

If the voltage at the pin EN is below a threshold of  $V_{\text{EN(off)}}$  the Basic LED Driver IC will enter Sleep mode. In this state all internal functions are switched off, the current consumption is reduced to  $I_{\text{S(sleep)}}$ . A voltage above  $V_{\text{EN(on)}}$  at this pin enables the device after the Power on reset time  $t_{\text{POR}}$ .







**EN Pin** 

(1)

## 5.2 Internal Supply Pin

The EN pin can be used to supply the internal logic. There are two typical application conditions, where this feature can be used:

1) In "DC/DC control Buck" configurations, where the voltage  $V_{\rm s}$  can be below 5.5V.

2) In configurations, where a PWM signal is applied at the Vbatt pin of a light module. The buffer capacitor  $C_{\text{BUF}}$  is used to supply the Basic LED Driver IC during Vbatt low ( $V_{\text{s}}$  low) periods. This feature can be used to minimize the turn-on time to the values specified in **Pos. 11.2.15**. Otherwise, the power-on reset delay time  $t_{\text{POR}}$  (**Pos. 6.3.8**) has to be considered.

The capacitor can be calculated using the following formula:

$$C_{\rm BUF} = t_{\rm LOW(max)} \cdot \frac{I_{\rm EN(LS)}}{V_{\rm S} - V_{\rm D1} - V_{\rm S(POR)}}$$

See also a typical application drawing in Chapter 12.

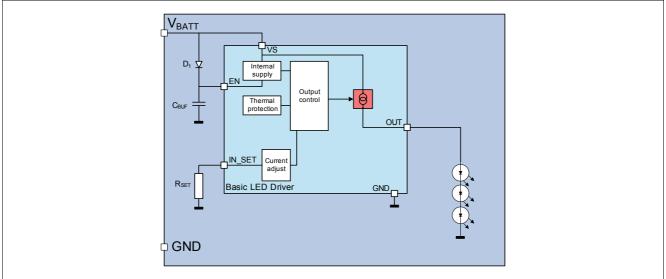


Figure 5 External circuit when applying a fast PWM signal on  $V_{\text{BATT}}$ 



#### EN Pin

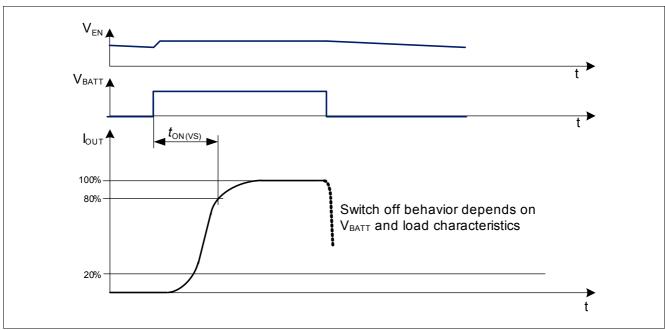


Figure 6 Typical waveforms when applying a fast PWM signal on  $V_{\text{BATT}}$ 

The parameter  $t_{ON(VS)}$  is defined at **Pos. 11.2.15**. The parameter  $t_{OFF(VS)}$  depends on the load and supply voltage  $V_{BATT}$  characteristics.

## 5.3 EN Unused

In case of an unused EN pin, there are two different ways to connect it:

## 5.3.1 EN - Pull Up to VS

The EN pin can be connected with a pull up resistor (e.g. 10 k $\Omega$ ) to  $V_s$  potential. In this configuration the Basic LED Driver IC is always enabled.

## 5.3.2 EN - Direct Connection to VS

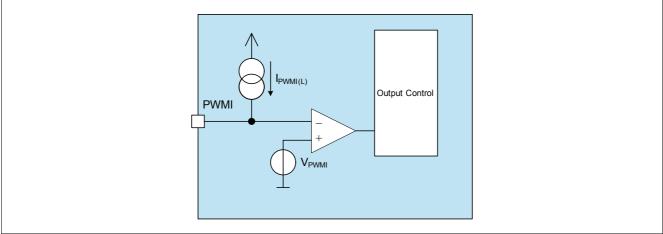
The EN pin can be connected directly to the VS pin (IC always enabled). This configuration has the advantage (compared to the configuration described in **Chapter 5.3.1**) that no additional external component is required.



**PWMI** Pin

## 6 PWMI Pin

The PWMI pin is designed as a dual function pin.



#### Figure 7 Block Diagram PWMI pin

The pin can be used for PWM-dimming via a push-pull stage of a micro controller, which is connecting the PWMIpin to a low or high potential.

Note: The micro controller's push-pull stage has to able to sink currents according to **Pos. 6.3.18** to activate the device.

Furthermore, the device offers also an internal PWM unit by connecting an external-RC network according to **Figure 10**.

## 6.1 **PWM Dimming**

A PWM signal can be applied at the PWMI pin for LED brightness regulation. The dimming frequency can be adjusted in a very wide range (e.g. 400 Hz). The PWMI pin is low active. Turn on/off thresholds  $V_{\text{PWMI(L)}}$  and  $V_{\text{PWMI(H)}}$  are specified in parameters **Pos. 6.3.15** and **Pos. 6.3.16**.

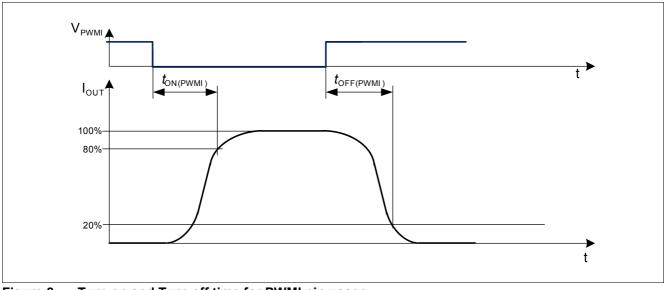


Figure 8 Turn on and Turn off time for PWMI pin usage



#### **PWMI** Pin

## 6.2 Internal PWM Unit

Connecting a resistor and a capacitor in parallel on the PWMI pin enables the internal pulse width modulation unit. The following figure shows the charging and discharging defined by the RC-network according to **Figure 10** and the internal PWM unit.

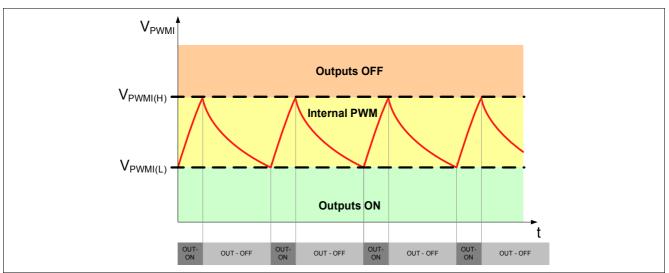


Figure 9 PWMI operating voltages

The PWM Duty cycle (DC) and the PWM frequency can be adjusted using the formulas below. Please use only typical values of  $V_{\text{PWMI(L)}}$ ,  $V_{\text{PWMI(H)}}$  and  $I_{\text{PWMI(on)}}$  for the calculation of  $t_{\text{PWMI(on)}}$  and  $t_{\text{PWMI(off)}}$  (as described in **Pos. 6.3.15** to **Pos. 6.3.18**).

$$t_{\rm PWMI(on)} = -R_{\rm PWMI} \cdot C_{\rm PWMI} \cdot LN \left( \frac{V_{\rm PWMI(H)} - I_{\rm PWMI(on)} \cdot R_{\rm PWMI}}{V_{\rm PWMI(L)} - I_{\rm PWMI(on)} \cdot R_{\rm PWMI}} \right)$$
(2)

$$t_{\rm PWMI(off)} = R_{\rm PWMI} \cdot C_{\rm PWMI} \cdot LN\left(\frac{V_{\rm PWMI(H)}}{V_{\rm PWMI(L)}}\right)$$
(3)

$$f_{\rm PWMI} = \frac{1}{t_{\rm PWMI(on)} + t_{\rm PWMI(off)}}$$
(4)

$$DC = t_{PWMI(on)} \cdot f_{PWMI}$$

Out of this equations the required  $C_{\text{PWMI}}$  and  $R_{\text{PWMI}}$  can be calculated:

$$C_{PWMI} = \frac{-I_{PWMI(on)} \cdot t_{PWMI(off)} \cdot \left[ \left( \frac{V_{PWMI(L)}}{V_{PWMI(H)}} \right)^{\frac{t_{PWMI(on)}}{t_{PWMI(off)}} - 1} \right]$$

$$C_{PWMI} = \frac{1}{LN\left( \frac{V_{PWMI(L)}}{V_{PWMI(L)}} \right) \cdot \left[ V_{PWMI(L)} \cdot \left( \frac{V_{PWMI(L)}}{V_{PWMI(H)}} \right)^{\frac{t_{PWMI(on)}}{t_{PWMI(off)}} - V_{PWMI(H)}} \right]$$

$$R_{PWMI} = \frac{t_{PWMI(off)}}{C_{PWMI} \cdot LN\left( \frac{V_{PWMI(H)}}{V_{PWMI(L)}} \right)}$$

$$(6)$$

(5)



See Figure 10 for a typical external circuitry.

Note: In case of junction temperatures above  $T_{j(CRT)}$  (**Pos. 11.2.16**) the device provides a temperature dependent current reduction feature as descirbed in **Chapter 11.1.1**. In case of output current reduction  $I_{IN\_SET}$  is reduced as well, which leads to increased turn on-times  $t_{PWMI(on)}$ , because the  $C_{PWMI}$  is charged slower. The turn off-time  $t_{PWMI(off)}$  remains the same.

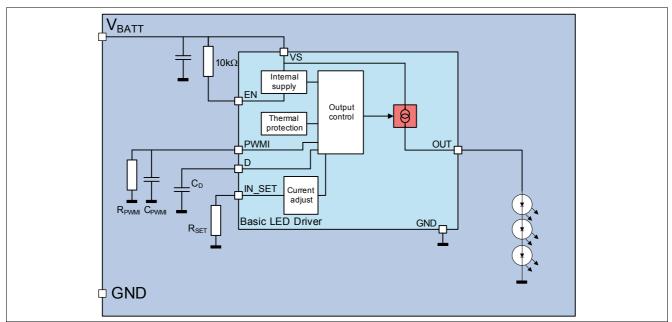


Figure 10 Typical circuit using internal PWM unit

## 6.3 Electrical Characteristics Internal Supply / EN / PWMI Pin

#### Electrical Characteristics Internal Supply / EN / PWMI pin

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$  all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol		Limit Val	ues	Unit	Conditions
			Min.	Тур.	Max.		
6.3.1	Current consumption, sleep mode	$I_{\rm S(sleep)}$	-	0.1	2	μΑ	<sup>1)</sup> $V_{\rm EN}$ = 0.5 V $T_{\rm j}$ < 85 °C $V_{\rm S}$ = 18 V $V_{\rm OUT}$ = 3.6 V
6.3.2	Current consumption, active mode	I <sub>S(on)</sub>			1.4 0.75 1.5	mA	<sup>2)</sup> $V_{PWMI} = 0.5 V$ $I_{IN_SET} = 0 \mu A$ $T_j < 105 °C$ $V_S = 18 V$ $V_{OUT} = 3.6V$ $V_{EN} = 5.5 V$ $V_{EN} = 18 V$ <sup>1)</sup> $R_{EN} = 10 k\Omega$ between VS and EN-pin



**PWMI** Pin

#### Electrical Characteristics Internal Supply / EN / PWMI pin (cont'd)

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$  all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.	]	
6.3.3	Current consumption,	$I_{\rm S(dis,ST)}$				mA	<sup>2)</sup> V <sub>S</sub> = 18 V
	device disabled via ST	0(0.0,01)					<i>T</i> <sub>i</sub> < 105 °C
							$V_{ST} = 5 V$
			_	_	1.4		$V_{\rm EN} = 5.5  \rm V$
			_	_	0.65		$V_{\rm EN} = 18 \text{ V}$
			_	_	1.4		$^{(1)}R_{\rm FN}$ = 10 k $\Omega$ between
					1.4		VS and EN-pin
5.3.4	Current consumption,	$I_{\rm S(dis,IN\_SET)}$				mA	$^{2)}V_{\rm S}$ = 18 V
	device disabled via IN_SET	-3(uis,IIN_3ET)					<i>T</i> <sub>i</sub> < 105 °C
	_						$V_{\text{IN}\_\text{SET}} = 5 \text{ V}$
			_	_	1.4		$V_{\rm EN} = 5.5 \rm V$
			_	_	0.7		V <sub>EN</sub> = 18 V
			_	_	1.4		<sup>1)</sup> $R_{\rm FN}$ = 10 k $\Omega$ between
							VS and EN-pin
6.3.5	Current consumption,	I <sub>S(dis,PWMI)</sub>				mA	$^{2)}V_{\rm S}$ = 18 V
	device disabled via PWMI	-S(dis,Pvvivii)					<i>T</i> <sub>i</sub> < 105 °C
							$V_{\text{PWMI}} = 3.4 \text{ V}$
					1.6		$V_{\rm EN} = 5.5 \mathrm{V}$
					0.75		$V_{\rm EN} = 3.0$ V $V_{\rm EN} = 18$ V
			-	-			
			-	-	1.6		<sup>1)</sup> $R_{\rm EN}$ = 10 k $\Omega$ between
							VS and EN-pin
6.3.6	Current consumption,	$I_{\rm S(fault,STu)}$				mA	<sup>2)</sup> $V_{\rm S}$ = 18 V
	active mode in fault						<i>T</i> <sub>j</sub> < 105 °C
	detection condition with ST-						$R_{\rm SET}$ = 12 k $\Omega$
	pin unconnected						$V_{PWMI}$ = 0.5 V
							V <sub>OUT</sub> = 18 V or 0 V
			-	-	1.7		V <sub>EN</sub> = 5.5 V
			-	-	1.1		V <sub>EN</sub> = 18 V
			_	-	1.8		<sup>1)</sup> $R_{\rm EN}$ = 10 k $\Omega$ between
							VS and EN-pin
6.3.7	Current consumption,	$I_{\rm S(fault,STG)}$				mA	<sup>2)</sup> V <sub>S</sub> = 18 V
	active mode in fault						T <sub>i</sub> < 105 °C
	detection condition with ST-						$\dot{R}_{SFT}$ = 12 k $\Omega$
	pin connected to GND						$V_{\rm PWMI} = 0.5 V$
							$V_{OUT}$ = 18 V or 0 V
							$V_{\rm ST} = 0 V$
			_	_	6.0		$V_{\rm EN} = 5.5 \rm V$
			_	_	4.9		$V_{\rm EN} = 3.0$ V $V_{\rm EN} = 18$ V
					4.9 5.9		$^{1)}R_{\rm EN}$ = 10 k $\Omega$ between
			-	-	5.8		VS and EN-pin
6.3.8	Power-on reset delay time <sup>3)</sup>	t			25	μs	<sup>1)</sup> $V_{\rm S} = V_{\rm FN} = 0 \rightarrow 13.5 \rm V$
0.0.0	i ower-on reset delay tille '	t <sub>POR</sub>			25	μο	$V_{\rm S} = V_{\rm EN} = 0 \Rightarrow 13.3 \text{ V}$ $V_{\rm OUT(nom)} = 3.6 \pm 0.3 \text{ V}$
							$I_{OUT} = 80\% I_{OUT(nom)}$
							<sup>1</sup> OUT - 00 /0 <sup>1</sup> OUT(nom)



#### **PWMI** Pin

#### Electrical Characteristics Internal Supply / EN / PWMI pin (cont'd)

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$  all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol		Limit Value	es	Unit	Conditions
			Min.	Тур.	Max.		
6.3.9	Required supply voltage for output activation	$V_{\mathrm{S(on)}}$	-	-	4	V	$V_{\rm EN}$ = 5.5 V $V_{\rm OUT}$ = 3 V $I_{\rm OUT}$ = 50% $I_{\rm OUT(nom)}$
6.3.10	Required supply voltage for current control	V <sub>S(CC)</sub>	-	-	5.2	V	$V_{\rm EN}$ = 5.5 V $V_{\rm OUT}$ = 3.6 V $I_{\rm OUT}$ ≥ 90% $I_{\rm OUT(nom)}$
6.3.11	EN turn on threshold	$V_{\rm EN(on)}$	_	_	2.5	V	-
6.3.12	EN turn off threshold	$V_{\rm EN(off)}$	0.8	-	_	V	_
6.3.13	EN input current during low supply voltage	I <sub>EN(LS)</sub>	-	-	1.8	mA	<sup>1)</sup> $V_{\rm S}$ = 4.5 V $T_{\rm j}$ < 105 °C $V_{\rm EN}$ = 5.5 V
6.3.14	EN high input current	I <sub>EN(H)</sub>			0.1 0.1 1.65 0.45	mA	$T_{\rm j}$ < 105 °C $V_{\rm S}$ = 13.5 V, $V_{\rm EN}$ = 5.5 V $V_{\rm S}$ = 18 V, $V_{\rm EN}$ = 5.5 V $V_{\rm S}$ = $V_{\rm EN}$ = 18 V <sup>1)</sup> $V_{\rm S}$ = 18 V, $R_{\rm EN}$ = 10 kΩ between VS and EN-pin
6.3.15	PWMI (active low) Switching low threshold (output on)	$V_{PWMI(L)}$	1.5	1.85	2.3	V	$^{(1)4)}V_{\rm S} = 818$ V
6.3.16	PWMI(active low) Switching high threshold (output off)	V <sub>PWMI(H)</sub>	2.45	2.85	3.2	V	<sup>1)4)5)</sup> $V_{\rm S}$ = 818 V
6.3.17	PWMI           Switching threshold           difference $V_{\text{PWMI(H)}}$ - $V_{\text{PWMI(L)}}$	$\Delta V_{PWMI}$	0.75	1	1.10	V	<sup>1)4)5)</sup> $V_{\rm S}$ = 818 V
6.3.18	PWMI (active low) Low input current with active channels (voltage <v<sub>PWMI(L))</v<sub>	I <sub>PWMI(on)</sub>	I <sub>IN_SET</sub> *3.1	I <sub>IN_SET</sub> *4	I <sub>IN_SET</sub> *4.9	μA	<sup>1)</sup> $T_{\rm j}$ = 25115 °C $I_{\rm IN_SET}$ = 100 µA $V_{\rm PWMI}$ = 1.7 V $V_{\rm EN}$ = 5.5 V $V_{\rm S}$ = 818 V
6.3.19	PWMI(active low) High input current	$I_{PWMI(off)}$	-5	-	5	μA	$V_{\rm PWMI}$ = 5 V $V_{\rm EN}$ = 5.5 V $V_{\rm S}$ = 818 V

1) Not subject to production test, specified by design

2) The total device current consumption is the sum of the currents  $I_{\rm S}$  and  $I_{\rm EN(H)}$ , please refer to Pos. 6.3.14

3) See also Figure 4

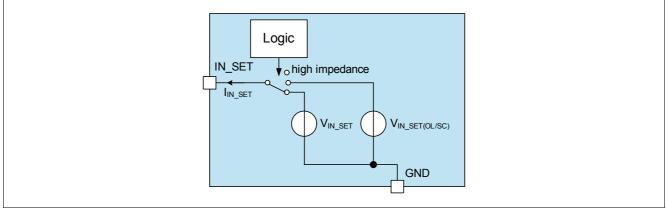
4) Parameter valid if an external PWM signal is applied

5) If TTL level compatibility is required, use  $\mu C$  open drain output with pull up resistor



## 7 IN\_SET Pin

The IN\_SET pin is a multiple function pin for output current definition, input and diagnostics:



#### Figure 11 Block Diagram IN\_SET pin

## 7.1 Output Current Adjustment via RSET

The current adjustment can be done by placing a low power resistor ( $R_{SET}$ ) at the IN\_SET pin to ground. The dimensioning of the resistor can be done using the formula below:

$$R_{\rm SET} = \frac{k}{I_{\rm OUT}} \tag{8}$$

The gain factor k ( $R_{\text{SET}}$  \* output current) is specified in **Pos. 11.2.4** and **Pos. 11.2.5**. The current through the  $R_{\text{SET}}$  is defined by the resistor itself and the reference voltage  $V_{\text{IN\_SET(ref)}}$ , which is applied to the IN\_SET during supplied device.

## 7.2 Smart Input Pin

The IN\_SET pin can be connected via  $R_{SET}$  to the open-drain output of a µC or to an external NMOS transistor as described in Figure 12. This signal can be used to turn off the output stage of the IC. A minimum IN\_SET current of  $I_{IN\_SET(act)}$  is required to turn on the output stage. This feature is implemented to prevent glimming of LEDs caused by leakage currents on the IN\_SET pin, see Figure 15 for details. In addition, the IN\_SET pin offers the diagnostic feedback information, if the status pin is connected to GND. Another diagnostic possibility is shown in Figure 13, where the diagnosis information is provided via the ST pin (refer to Chapter 8 and Chapter 10) to a micro controller. In case of a fault event with the ST pin connected to GND the IN\_SET voltage is increased to  $V_{IN\_SET(OL/SC)}$  Pos. 10.3.2. Therefore, the device has two voltage domains at the IN\_SET-pin, which is shown in Figure 16.



#### **IN\_SET** Pin

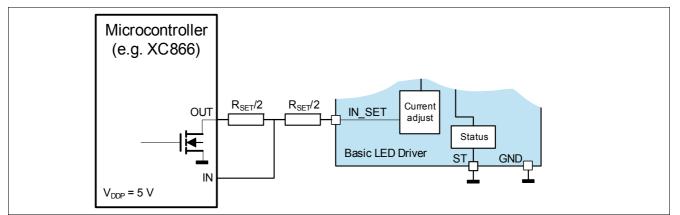


Figure 12 Schematics IN\_SET interface to µC, diagnosis via IN\_SET pin

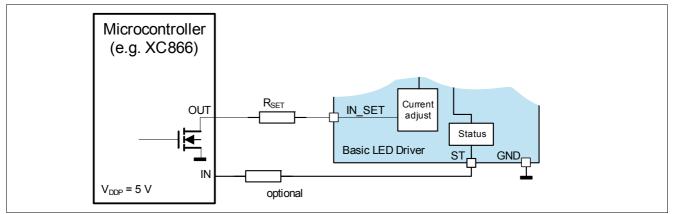


Figure 13 Schematics IN\_SET interface to µC, diagnosis via ST pin

The resulting switching times are shown in Figure 14:

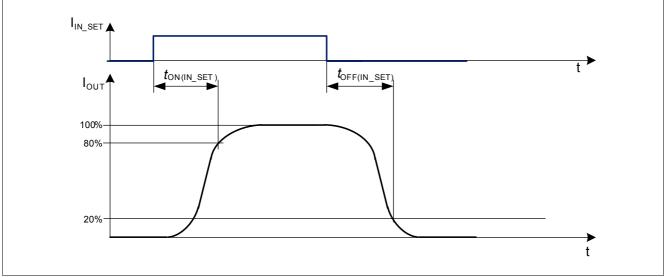
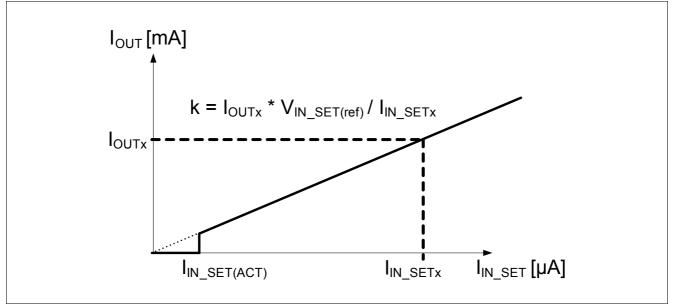


Figure 14 Switching times via IN\_SET



#### **IN\_SET** Pin





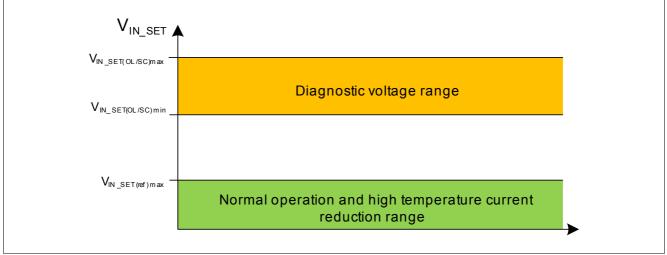


Figure 16 Voltage domains for IN\_SET pin, if ST pin is connected to GND



ST Pin

## 8 ST Pin

The ST pin is a multiple function pin.

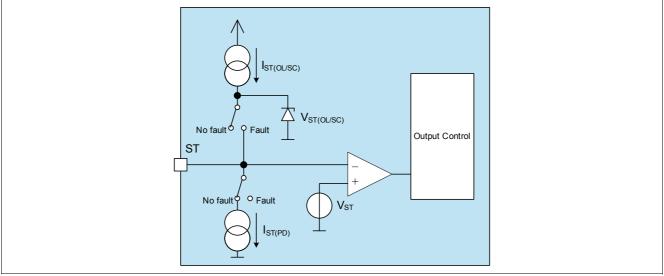


Figure 17 Block Diagram ST pin

## 8.1 Diagnosis Selector

If the status pin is unconnected or connected to GND via a high ohmic resistor ( $V_{\text{ST}}$  to be below  $V_{\text{ST(L)}}$ ), the ST pin acts as diagnosis output pin. In normal operation (device is activated) the ST pin is pulled to GND via the internal pull down current  $I_{\text{ST(PD)}}$ . In case of an open load or short circuit to GND condition the ST pin is switched to  $V_{\text{ST(OL/SC)}}$  after the filter time $t_{\text{D}}$  (see Equation (11)).

If the device is operated in PWM operation via the VS and/or EN pins the ST pin should be connected to GND via a high ohmic resistor (e.g.  $470k\Omega$ ) to ensure proper device behavior during fast rising VS and/or EN slopes.

If the ST pin is shorted to GND the diagnostic feedback is performed via the IN\_SET-pin, which is shown in **Chapter 7.2** and **Chapter 10**.

## 8.2 Diagnosis Output

If the status pin is unconnected or connected to GND via a high ohmic resistor ( $V_{ST}$  to be below  $V_{ST(L)}$ ), it acts as a diagnostic output. In case of a fault condition the ST pin rises its voltage to  $V_{ST(OL/SC)}$  (**Pos. 10.3.7**). Details are shown in **Chapter 10**.

## 8.3 Disable Input

If an external voltage higher than  $V_{\text{ST(H)}}$  (**Pos. 10.3.5**) is applied to the ST pin, the device is switched off. This function is used for applications, where multiple drivers should be used for one light function. It is possible to combine the drivers' fault diagnosis via the ST pins. If a single LED chain fails, the entire light function is switched off. In this scenario e.g. the diagnostic circuit on the body control module can easily distinguish between the two cases (normal load or load fault), because nearly no current is flowing into the LED module during the fault scenario - the drivers consume a current of  $I_{\text{S(fault,STu)}}$  (**Pos. 6.3.6**) or  $I_{\text{S(dis,ST)}}$  (**Pos. 6.3.3**).

As soon as one LED chain fails, the ST-pin of this device is switched to  $V_{\text{ST(OL/SC)}}$ . The other devices used for the same light function can be connected together via the ST pins. This leads to a switch off of all devices connected together. Application examples are shown in **Chapter 12**.



#### ST Pin

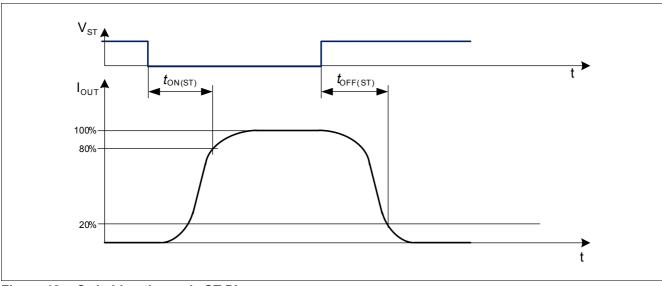


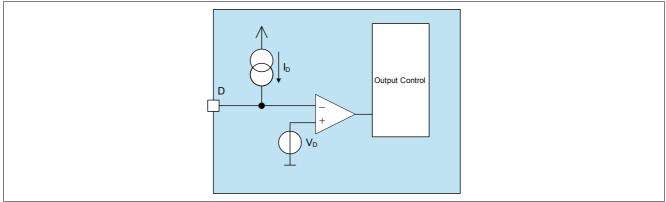
Figure 18 Switching times via ST Pin



D Pin

## 9 D Pin

The D pin is designed as a single function pin.



#### Figure 19 Block Diagram DIS pin

The D pin can be used to extend the open load detection filter time  $t_{OL}$  by adding a small signal capacitor to the D pin as shown in **Figure 26**. The filter time  $t_D$ , which is defined by the charging current  $I_D$  (**Pos. 10.3.10**). The time is adjustable according to the following equation:

$$t_{\rm typ} = \frac{C_{\rm D} \cdot V_{\rm D(th)}}{I_{\rm D}}$$
(9)



## 10 Load Diagnosis

### 10.1 Open Load

An open load diagnosis feature is integrated in the TLD1125EL driver IC. If there is an open load on the output, the output is turned off. The potential on the IN\_SET pin rises up to  $V_{\text{IN}\_\text{SET}(\text{OL/SC})}$ . This high voltage can be used as input signal for an  $\mu$ C as shown in **Figure 13**. The open load status is not latched, as soon as the open load condition is no longer present, the output stage will be turned on again. An open load condition is detected, if the voltage drop over the output stage  $V_{\text{PS}}$  is below the threshold according **Pos. 10.3.11**. The output is deactivated after a filter time  $t_{\text{D}}$ , which is defined by the charging current  $I_{\text{D}}$  **Pos. 10.3.10**. The time is adjustable by the capacitor connected to the D pin according the following equation:

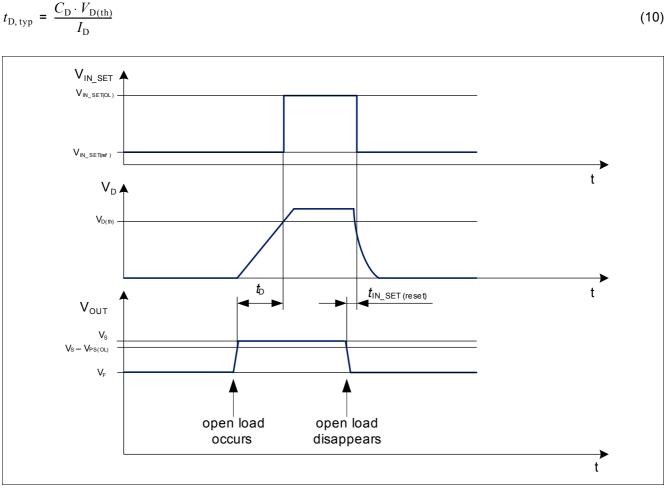


Figure 20 IN\_SET behavior during open load condition with ST pin connected to GND



#### Load Diagnosis

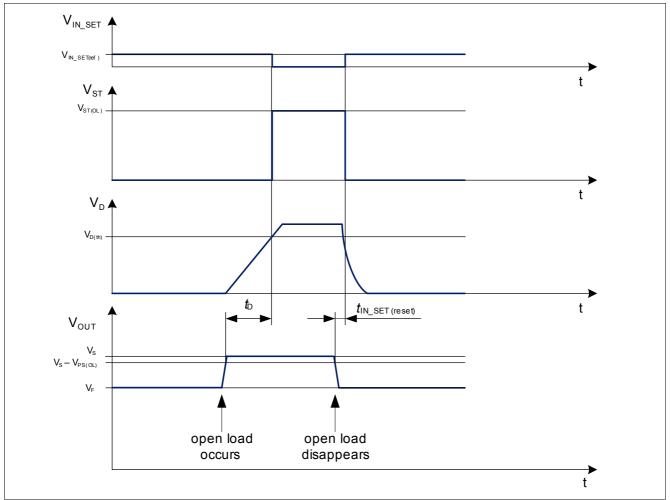


Figure 21 IN\_SET and ST behavior during open load condition (ST unconnected)

To provide a Limp Home functionality (reactivation in case of open load instead of complete deactivation) the filter time  $t_D$  can be used. If a PWM signal with a frequency higher than  $1/t_D$  is applied to the  $V_S$  line and EN signal, the OL detection feature will not be activated. The implementation of the D-pin is shown in the following figure:

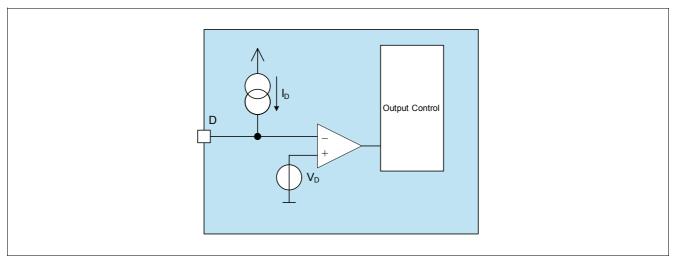


Figure 22 Block Diagram D pin



#### Load Diagnosis

## 10.2 Short Circuit to GND detection

The TLD1125EL has an integrated SC to GND detection. If the output stage is turned on and the voltage at the output falls below  $V_{\text{OUT(SC)}}$  the potential on the IN\_SET pin is increased up to  $V_{\text{IN}\_\text{SET(OL/SC)}}$  after  $t_{\text{SC}}$  if the ST pin is connected to GND. If the ST is open or connected to GND via a high ohmic resistor the fault is indicated on the ST pin according to **Chapter 8** after  $t_{\text{D}}$ . More details are shown in **Figure 24**. This condition is not latched. For detecting a normal condition after a short circuit detection an output current according to  $I_{\text{OUT(SC)}}$  is driven by the channel.

The filter time  $t_D$  is defined by the charging current  $I_D$  **Pos. 10.3.10**. The time is adjustable by the capacitor connected to the D pin according the following equation:

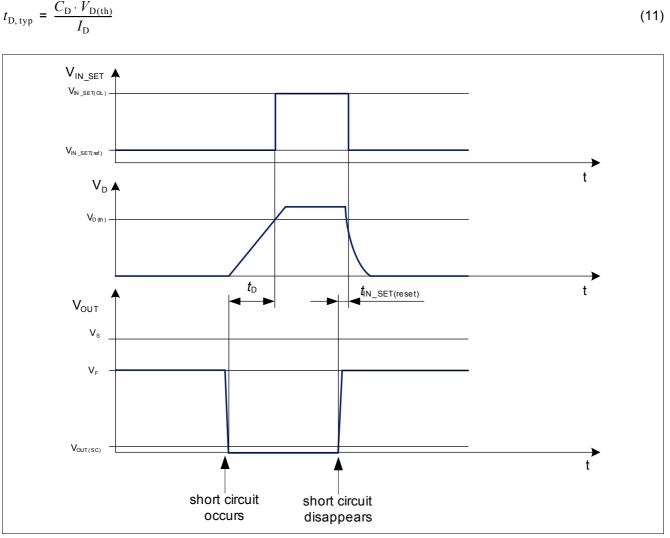
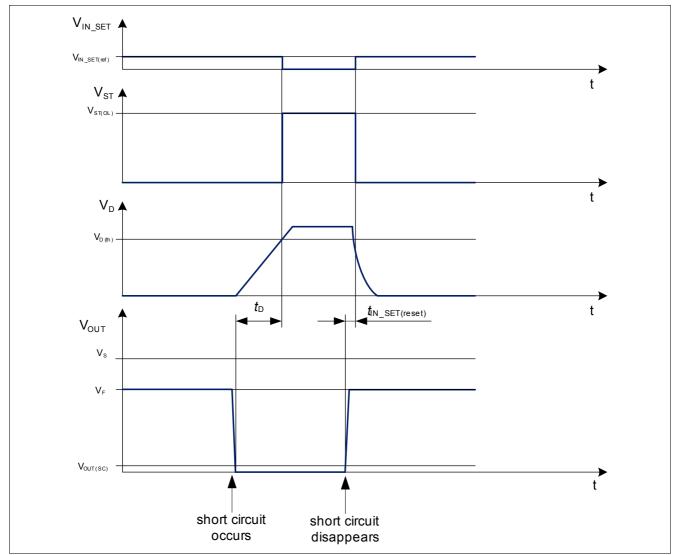
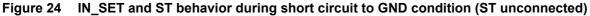


Figure 23 IN\_SET behavior during short circuit to GND condition with ST connected to GND



#### Load Diagnosis





## 10.3 Electrical Characteristics IN\_SET Pin and Load Diagnosis

#### Electrical Characteristics IN\_SET pin and Load Diagnosis

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$ , all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol Limit Values				Unit	Conditions	
			Min.	Тур.	Max.			
10.3.1	IN_SET reference voltage	$V_{\rm IN\_SET(ref)}$	1.19	1.23	1.27	V	<sup>1)</sup> $V_{OUT} = 3.6 V$ $T_i = 25115 °C$	
10.3.2	IN_SET open load/short circuit voltage	V <sub>IN_SET(OL/SC)</sub>	4	-	5.5	V	<sup>1)</sup> $V_{\rm S}$ > 8 V $T_{\rm j}$ = 25150 °C $V_{\rm S}$ = $V_{\rm OUT}$ (OL) or $V_{\rm OUTx}$ = 0 V (SC)	



#### Load Diagnosis

#### Electrical Characteristics IN\_SET pin and Load Diagnosis (cont'd)

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$ , all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions	
			Min.	Тур.	Max.			
10.3.3	IN_SET open load/short circuit current	I <sub>IN_SET(OL/SC)</sub>	1.5	-	7.4	mA	<sup>1)</sup> $V_{\rm S}$ > 8 V $T_{\rm j}$ = 25150 °C $V_{\rm IN\_SET}$ = 4 V $V_{\rm S}$ = $V_{\rm OUT}$ (OL) or $V_{\rm OUT}$ = 0 V (SC)	
10.3.4	ST device turn on threshold (active low) in case of voltage applied from external (ST-pin acting as input)	V <sub>ST(L)</sub>	0.8	-	-	V	_	
10.3.5	ST device turn off threshold (active low) in case of voltage applied from external (ST-pin acting as input)	$V_{\rm ST(H)}$	_	-	2.5	V	-	
10.3.6	ST pull down current	I <sub>ST(PD)</sub>	-	-	15	μA	$V_{\rm EN} = 5.5 V$ $V_{\rm ST} = 0.8 V$	
10.3.7	ST open load/short circuit voltage (ST-pin acting as diagnosis output)	$V_{\rm ST(OL/SC)}$	4	-	5.5	V	<sup>1)</sup> $V_{\rm S} > 8 \text{ V}$ $T_{\rm j} = 25150 \text{ °C}$ $R_{\rm ST} = 470 \text{ k}\Omega$ $V_{\rm S} = V_{\rm OUT} \text{ (OL) or } V_{\rm OUT} =$ 0  V (SC)	
10.3.8	ST open load/short circuit current (ST-pin acting as diagnosis output)	I <sub>ST(OL/SC)</sub>	100	-	220	μA	<sup>1)</sup> $V_{\rm S}$ > 8 V $T_{\rm j}$ = 25150 °C $V_{\rm ST}$ = 2.5 V $V_{\rm S}$ = $V_{\rm OUT}$ (OL) or $V_{\rm OUT}$ = 0 V (SC)	
10.3.9	D high threshold	$V_{D(th)}$	2.45	2.85	3.2	V	V <sub>S</sub> > 8 V	
10.3.10	D output current	I <sub>D</sub>	1	2	3	μA	$V_{\rm S}$ > 8 V $V_{\rm D}$ = 2 V	
10.3.11	OL detection voltage $V_{PS(OL)} = V_S - V_{OUT}$	V <sub>PS(OL)</sub>	0.2	-	0.4	V	V <sub>S</sub> > 8 V	
10.3.12	Short circuit to GND detection threshold	V <sub>OUT(SC)</sub>	0.8	-	1.4	V	V <sub>S</sub> > 8 V	
10.3.13	IN_SET diagnosis reset time	t <sub>IN_SET(reset)</sub>	-	5	20	μs	<sup>1)</sup> V <sub>S</sub> > 8 V	
10.3.14	SC detection current in case of unconnected ST- pin	I <sub>OUT(SC,STu)</sub>	100	200	300	μA	V <sub>S</sub> > 8 V V <sub>OUT</sub> = 0 V	



#### Load Diagnosis

#### Electrical Characteristics IN\_SET pin and Load Diagnosis (cont'd)

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 40 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $R_{\rm SET}$  = 12 k $\Omega$ , all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
10.3.15	SC detection current in case of ST-pin shorted to GND	I <sub>OUT(SC,STG)</sub>	0.1	2	4.75	mA	$V_{\rm S} > 8 V$ $V_{\rm OUT} = 0 V$ $V_{\rm ST} = 0 V$
10.3.16	IN_SET activation current without turn on of output stage	I <sub>IN_SET(act)</sub>	2	-	15	μA	See Figure 15

1) Not subject to production test, specified by design



## 11 Power Stage

The output stage is realized as high side current source with a current of 360 mA. During off state the leakage current at the output stage is minimized in order to prevent a slightly glowing LED.

The maximum current of the channel is limited by the power dissipation and used PCB cooling areas (which results in the applications  $R_{\text{thJA}}$ ).

For an operating current control loop the supply and output voltages according to the following parameters have to be considered:

- Required supply voltage for current control V<sub>S(CC)</sub>, Pos. 6.3.10
- Voltage drop over output stage during current control V<sub>PS(CC)</sub>, Pos. 11.2.6
- Required output voltage for current control V<sub>OUT(CC)</sub>, Pos. 11.2.7

#### 11.1 Protection

The device provides embedded protective functions, which are designed to prevent IC destruction under fault conditions described in this data sheet. Fault conditions are considered as "outside" normal operating range. Protective functions are neither designed for continuous nor for repetitive operation.

### 11.1.1 Over Load Behavior

An over load detection circuit is integrated in the Basic LED Driver IC. It is realized by a temperature monitoring of the output stage (OUT).

As soon as the junction temperature exceeds the current reduction temperature threshold  $T_{j(CRT)}$  the output current will be reduced by the device by reducing the IN\_SET reference voltage  $V_{IN\_SET(ref)}$ . This feature avoids LED's flickering during static output overload conditions. Furthermore, it protects LEDs against over temperature, which are mounted thermally close to the device. If the device temperature still increases, the output current decreases close to 0 A. As soon as the device cools down the output current rises again.

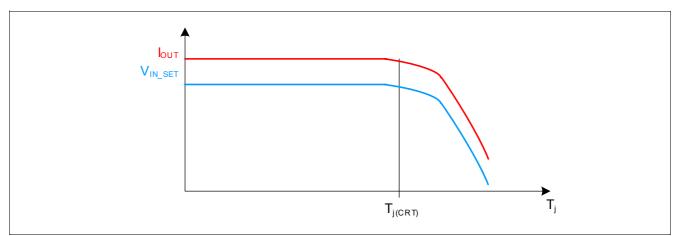


Figure 25 Output current reduction at high temperature

Note: This high temperature output current reduction is realized by reducing the IN\_SET reference voltage voltage (**Pos. 10.3.1**). In case of very high power loss applied to the device and very high junction temperature the output current may drop down to  $I_{OUT} = 0$  mA, after a slight cooling down the current increases again.

#### 11.1.2 Reverse Battery Protection

The TLD1125EL has an integrated reverse battery protection feature. This feature protects the driver IC itself, but also connected LEDs. The output reverse current is limited to  $I_{OUTx(rev)}$  by the reverse battery protection.



Note: Due to the reverse battery protection a reverse protection diode for the light module may be obsolete. In case of high ISO-pulse requirements and only minor protecting components like capacitors a reverse protection diode may be reasonable. The external protection circuit needs to be verified in the application.

## 11.2 Electrical Characteristics Power Stage

#### **Electrical Characteristics Power Stage**

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 18 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $V_{\rm OUT}$  = 3.6 V, all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter         Output leakage current	Symbol	Limit Values			Unit	Conditions	
			Min.	Тур.	Max.			
11.2.1			_	_	- 21	μA	$V_{\rm EN} = 5.5 V$ $I_{\rm IN\_SET} = 0 \mu A$ $V_{\rm OUT} = 2.5 V$ $T_{\rm J} = 150 ^{\circ}{\rm C}$	
11.2.2	Output leakage current in boost over battery setup	-I <sub>OUT(leak,B2B)</sub>	-	_	9 150	μA	<sup>1)</sup> $T_{j} = 85 \text{ °C}$ <sup>1)</sup> $V_{EN} = 5.5 \text{ V}$ $I_{IN_{SET}} = 0 \mu\text{A}$ $V_{OUT} = V_{S} = 40 \text{ V}$	
11.2.3	Reverse output current	-I <sub>OUT(rev)</sub>	-	-	3	μA	<sup>1)</sup> $V_{\rm S}$ = -16 V Output load: LED with break down voltage < - 0.6 V	
11.2.4	Output current accuracy limited temperature range	k <sub>LT</sub>	2092 1800	2250 2250	2408 2700		<sup>1)</sup> $T_{\rm j}$ = 25115 °C $V_{\rm S}$ = 818 V $V_{\rm PS}$ = 2 V $R_{\rm SET}$ = 12 kΩ $R_{\rm SET}$ = 30 kΩ	
11.2.5	Output current accuracy over temperature	k <sub>ALL</sub>	1980 1710	2250 2250	2520 2790		<sup>1)</sup> $T_{\rm j}$ = -40115 °C $V_{\rm S}$ = 818 V $V_{\rm PS}$ = 2 V $R_{\rm SET}$ = 612 kΩ $R_{\rm SET}$ = 30 kΩ	
11.2.6	Voltage drop over power stage during current control $V_{PS(CC)} = V_S - V_{OUT}$	V <sub>PS(CC)</sub>	0.75	-	-	V	<sup>1)</sup> $V_{\rm S}$ = 13.5 V $R_{\rm SET}$ = 12 k $\Omega I_{\rm OUT}$ ≥ 90% of ( $k_{\rm LT(typ)}/R_{\rm SET}$ )	
11.2.7	Required output voltage for current control	V <sub>OUT(CC)</sub>	2.3	-	-	V	<sup>1)</sup> $V_{\rm S} = 13.5 \text{ V}$ $R_{\rm SET} = 12 \text{ k}\Omega I_{\rm OUT} \ge 90\%$ of $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.8	Maximum output current	$I_{\rm OUT(max)}$	360	-	-	mA	$R_{SET}$ = 4.7 kΩ The maximum output current is limited by the thermal conditions. Please refer to <b>Pos. 4.3.1</b> - <b>Pos. 4.3.3</b>	



#### **Power Stage**

#### Electrical Characteristics Power Stage (cont'd)

Unless otherwise specified:  $V_{\rm S}$  = 5.5 V to 18 V,  $T_{\rm j}$  = -40 °C to +150 °C,  $V_{\rm OUT}$  = 3.6 V, all voltages with respect to ground, positive current flowing into pin for input pins (I), positive currents flowing out of the I/O and output pins (O) (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions	
			Min. Typ. Max.		1			
11.2.9	PWMI turn on time	t <sub>on(pwmi)</sub>	-	-	15	μs	<sup>2)</sup> $V_{\rm S}$ = 13.5 V $R_{\rm SET}$ = 12 k $\Omega$ PWMI $\rightarrow$ L $I_{\rm OUT}$ = 80% of $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.10	PWMI turn off time	t <sub>OFF(PWMI)</sub>	-	-	10	μs	<sup>2)</sup> $V_{\rm S}$ = 13.5 V $R_{\rm SET}$ = 12 k $\Omega$ PWMI $\rightarrow$ H $I_{\rm OUT}$ = 20% of $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.11	ST turn on time	t <sub>on(st)</sub>	-	-	15	μs		
11.2.12	ST turn off time	t <sub>OFF(ST)</sub>	-	-	10	μs	<sup>3)</sup> $V_{\rm S}$ = 13.5 V $R_{\rm SET}$ = 12 k $\Omega$ ST $\rightarrow$ H $I_{\rm OUT}$ = 20% of $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.13	IN_SET turn on time	t <sub>ON(IN_SET)</sub>	-	-	15	μs	$V_{\rm S} = 13.5 \text{ V}$ $I_{\rm IN\_SET} = 0 \rightarrow 100 \mu\text{A}$ $I_{\rm OUT} = 80\% \text{ of}$ $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.14	IN_SET turn off time	t <sub>OFF(IN_SET)</sub>	-	_	10	μs	$V_{\rm S} = 13.5 \text{ V}$ $I_{\rm IN\_SET} = 100 \rightarrow 0 \mu\text{A}$ $I_{\rm OUT} = 20\% \text{ of}$ $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.15	VS turn on time	t <sub>on(vs)</sub>	-	-	20	μs	<sup>1) 4)</sup> $V_{\rm EN}$ = 5.5 V $R_{\rm SET}$ = 12 kΩ $V_{\rm S}$ = 0 → 13.5 V $I_{\rm OUT}$ = 80% of $(k_{\rm LT(typ)}/R_{\rm SET})$	
11.2.16	Current reduction temperature threshold	$T_{\rm j(CRT)}$	_	140	-	°C	<sup>1)</sup> $I_{OUT}$ = 95% of ( $k_{LT(typ)}/R_{SET}$ )	
11.2.17	Output current during current reduction at high temperature	I <sub>OUT(CRT)</sub>	85% of (k <sub>LT(typ)</sub> / R <sub>SET</sub> )	-	-	A	<sup>1)</sup> $R_{SET}$ = 12 kΩ $T_{j}$ = 150 °C	

1) Not subject to production test, specified by design

2) see also Figure 8

3) see also Figure 18

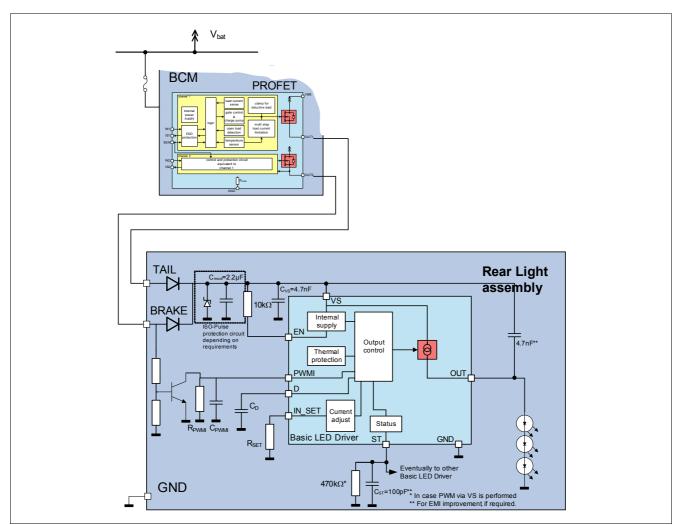
4) see also Figure 6



#### **Application Information**

## 12 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.



#### Figure 26 Application Diagram

Note: This is a very simplified example of an application circuit. In case of high ISO-pulse requirements a reverse protection diode may be used for LED protection. The function must be verified in the real application.

#### 12.1 Further Application Information

For further information you may contact http://www.infineon.com/



**Package Outlines** 

## 13 Package Outlines

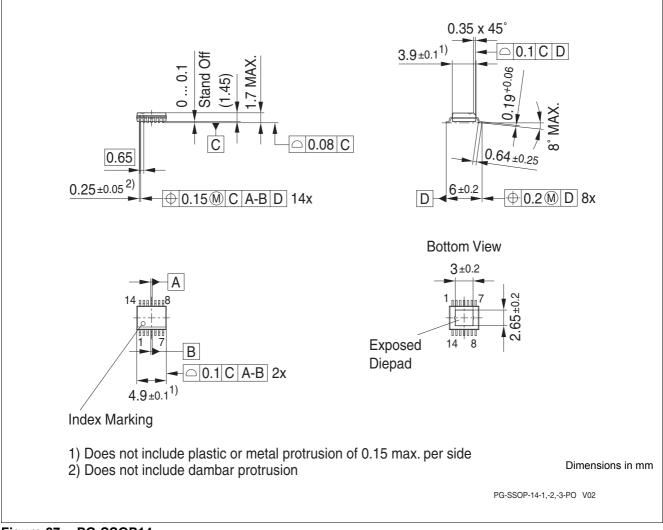


Figure 27 PG-SSOP14

#### Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.



#### **Revision History**

## 14 Revision History

Revision	Date	Changes
1.0	2013-08-08	Inital revision of data sheet

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#### Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

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Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.